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# FGH15T120SMD

## 1200 V, 15 A Field Stop Trench IGBT

### Features

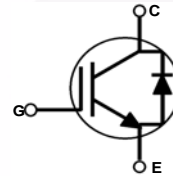
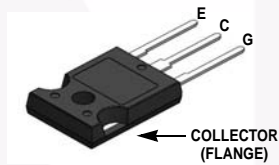
- FS Trench Technology, Positive Temperature Coefficient
- High Speed Switching
- Low Saturation Voltage:  $V_{CE(sat)} = 1.8 \text{ V}$  @  $I_C = 15 \text{ A}$
- 100% of The Parts Tested for  $I_{LM}(1)$
- High Input Impedance
- RoHS Compliant

### Applications

- Solar Inverter, Welder, UPS & PFC Applications.

### General Description

Using innovative field stop trench IGBT technology, Fairchild's new series of field stop trench IGBTs offer the optimum performance for hard switching application such as solar inverter, UPS, welder and PFC applications.



### Absolute Maximum Ratings $T_C = 25^\circ\text{C}$ unless otherwise noted

Symbol	Description	Ratings	Unit
$V_{CES}$	Collector to Emitter Voltage	1200	V
$V_{GES}$	Gate to Emitter Voltage	$\pm 25$	V
	Transient Gate to Emitter Voltage	$\pm 30$	V
$I_C$	Collector Current @ $T_C = 25^\circ\text{C}$	30	A
	Collector Current @ $T_C = 100^\circ\text{C}$	15	A
$I_{LM}(1)$	Clamped Inductive Load Current @ $T_C = 25^\circ\text{C}$	60	A
$I_{CM}(2)$	Pulsed Collector Current	60	A
$I_F$	Diode Continuous Forward Current @ $T_C = 25^\circ\text{C}$	30	A
	Diode Continuous Forward Current @ $T_C = 100^\circ\text{C}$	15	A
$I_{FM}$	Diode Maximum Forward Current	100	A
$P_D$	Maximum Power Dissipation @ $T_C = 25^\circ\text{C}$	333	W
	Maximum Power Dissipation @ $T_C = 100^\circ\text{C}$	167	W
$T_J$	Operating Junction Temperature	-55 to +175	$^\circ\text{C}$
$T_{stg}$	Storage Temperature Range	-55 to +175	$^\circ\text{C}$
$T_L$	Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 seconds	300	$^\circ\text{C}$

### Thermal Characteristics

Symbol	Parameter	Typ.	Max.	Unit
$R_{\theta JC}(\text{IGBT})$	Thermal Resistance, Junction to Case	--	0.45	$^\circ\text{C/W}$
$R_{\theta JC}(\text{Diode})$	Thermal Resistance, Junction to Case	--	2.0	$^\circ\text{C/W}$
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	--	40	$^\circ\text{C/W}$

#### Notes:

1.  $V_{CC} = 600 \text{ V}$ ,  $V_{GE} = 15 \text{ V}$ ,  $I_C = 60 \text{ A}$ ,  $R_G = 34 \Omega$ , Inductive Load
2. Limited by  $T_{jmax}$

**Package Marking and Ordering Information**

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FGH15T120SMD	FGH15T120SMD_F155	TO-247G03	-	-	30

**Electrical Characteristics of the IGBT**  $T_C = 25^\circ\text{C}$  unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
Off Characteristics						
BV <sub>CES</sub>	Collector to Emitter Breakdown Voltage	V <sub>GE</sub> = 0 V, I <sub>C</sub> = 250 uA	1200	-	-	V
I <sub>CES</sub>	Collector Cut-Off Current	V <sub>CE</sub> = V <sub>CES</sub> , V <sub>GE</sub> = 0 V	-	-	250	uA
I <sub>GES</sub>	G-E Leakage Current	V <sub>GE</sub> = V <sub>GES</sub> , V <sub>CE</sub> = 0 V	-	-	±400	nA
On Characteristics						
V <sub>GE(th)</sub>	G-E Threshold Voltage	I <sub>C</sub> = 15 mA, V <sub>CE</sub> = V <sub>GE</sub>	4.9	6.2	7.5	V
V <sub>CE(sat)</sub>	Collector to Emitter Saturation Voltage	I <sub>C</sub> = 15 A, V <sub>GE</sub> = 15 V T <sub>C</sub> = 25°C	-	1.8	2.4	V
		I <sub>C</sub> = 15 A, V <sub>GE</sub> = 15 V, T <sub>C</sub> = 175°C	-	1.9	-	V
Dynamic Characteristics						
C <sub>ies</sub>	Input Capacitance	V <sub>CE</sub> = 30 V, V <sub>GE</sub> = 0 V, f = 1MHz	-	1460	-	pF
C <sub>oes</sub>	Output Capacitance		-	65	-	pF
C <sub>res</sub>	Reverse Transfer Capacitance		-	37	-	pF
Switching Characteristics						
t <sub>d(on)</sub>	Turn-On Delay Time	V <sub>CC</sub> = 600 V, I <sub>C</sub> = 15 A, R <sub>G</sub> = 34 Ω, V <sub>GE</sub> = 15 V, Inductive Load, T <sub>C</sub> = 25°C	-	32	-	ns
t <sub>r</sub>	Rise Time		-	47	-	ns
t <sub>d(off)</sub>	Turn-Off Delay Time		-	490	-	ns
t <sub>f</sub>	Fall Time		-	12	-	ns
E <sub>on</sub>	Turn-On Switching Loss		-	1.15	-	mJ
E <sub>off</sub>	Turn-Off Switching Loss		-	0.46	-	mJ
E <sub>ts</sub>	Total Switching Loss	V <sub>CC</sub> = 600 V, I <sub>C</sub> = 15 A, R <sub>G</sub> = 34 Ω, V <sub>GE</sub> = 15 V, Inductive Load, T <sub>C</sub> = 175°C	-	1.61	-	mJ
t <sub>d(on)</sub>	Turn-On Delay Time		-	32	-	ns
t <sub>r</sub>	Rise Time		-	42	-	ns
t <sub>d(off)</sub>	Turn-Off Delay Time		-	510	-	ns
t <sub>f</sub>	Fall Time		-	24	-	ns
E <sub>on</sub>	Turn-On Switching Loss		-	1.86	-	mJ
E <sub>off</sub>	Turn-Off Switching Loss		-	0.70	-	mJ
E <sub>ts</sub>	Total Switching Loss		-	2.56	-	mJ
Q <sub>g</sub>	Total Gate Charge		V <sub>CE</sub> = 600 V, I <sub>C</sub> = 15 A, V <sub>GE</sub> = 15 V	-	128	-
Q <sub>ge</sub>	Gate to Emitter Charge	-		11	-	nC
Q <sub>gc</sub>	Gate to Collector Charge	-		70	-	nC

**Electrical Characteristics of the DIODE**  $T_C = 25^\circ\text{C}$  unless otherwise noted

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
$V_{FM}$	Diode Forward Voltage	$I_F = 15\text{ A}, T_C = 25^\circ\text{C}$	-	2.8	3.7	V
		$I_F = 15\text{ A}, T_C = 175^\circ\text{C}$	-	2.3	-	V
$t_{rr}$	Diode Reverse Recovery Time	$V_R = 600\text{ V}, I_F = 15\text{ A},$ $di_F/dt = 200\text{ A/us}, T_C = 25^\circ\text{C}$	-	72	-	ns
$I_{rr}$	Diode Peak Reverse Recovery Current		-	7.4	-	A
$Q_{rr}$	Diode Reverse Recovery Charge		-	270	-	nC
$E_{rec}$	Reverse Recovery Energy	$V_R = 600\text{ V}, I_F = 15\text{ A},$ $di_F/dt = 200\text{ A/us}, T_C = 175^\circ\text{C}$	-	120	-	$\mu\text{J}$
$t_{rr}$	Diode Reverse Recovery Time		-	183	-	ns
$I_{rr}$	Diode Peak Reverse Recovery Current		-	12	-	A
$Q_{rr}$	Diode Reverse Recovery Charge		-	1085	-	nC



## Typical Performance Characteristics

Figure 1. Typical Output Characteristics

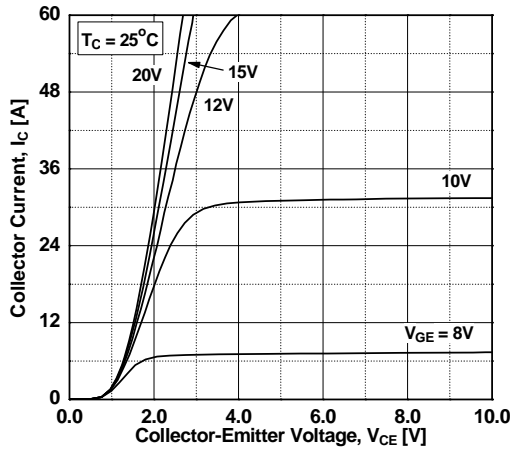


Figure 2. Typical Output Characteristics

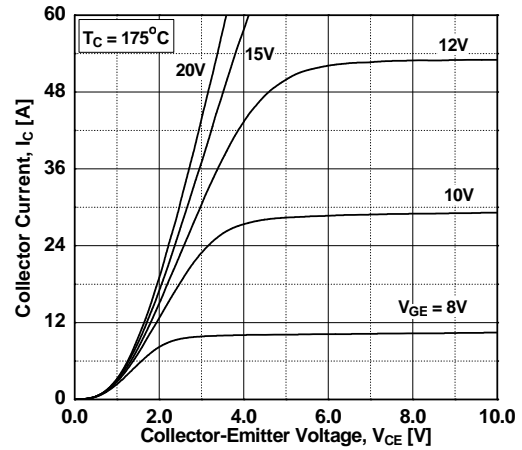


Figure 3. Typical Saturation Voltage Characteristics

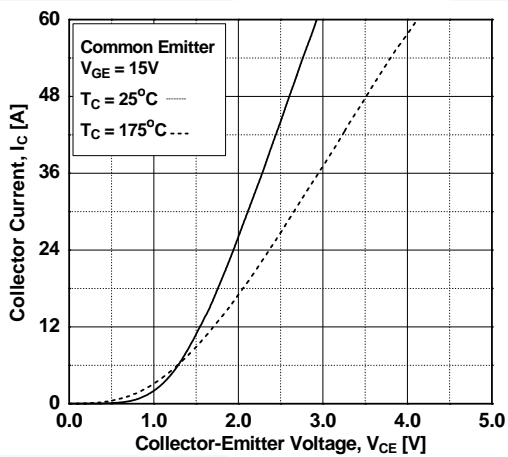


Figure 4. Saturation Voltage vs. Case Temperature at Variant Current Level

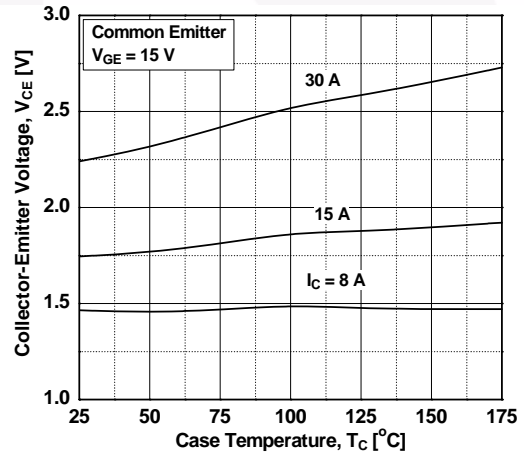


Figure 5. Saturation Voltage vs.  $V_{GE}$

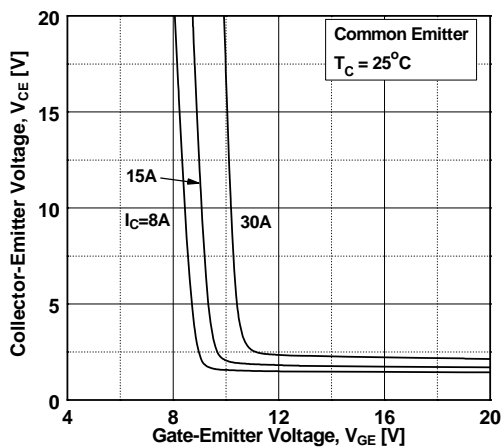
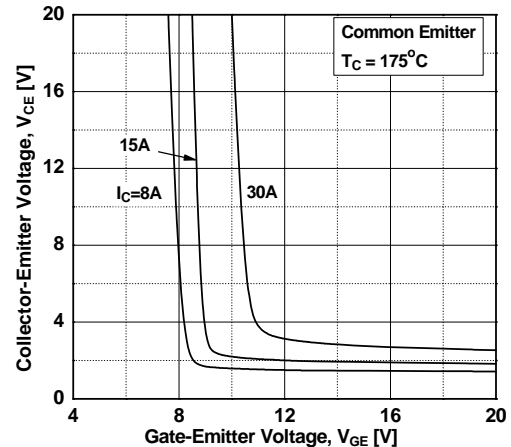


Figure 6. Saturation Voltage vs.  $V_{GE}$



## Typical Performance Characteristics

Figure 7. Capacitance Characteristics

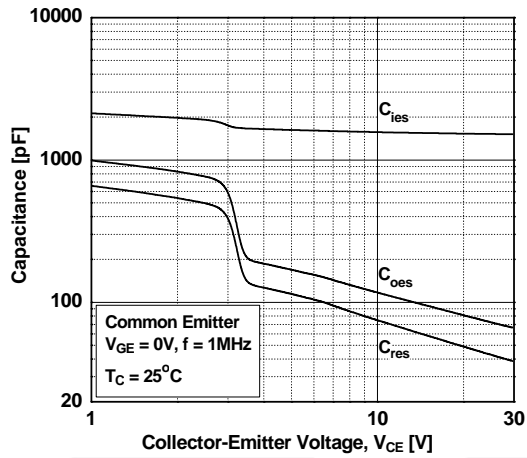


Figure 8. Gate Charge Characteristics

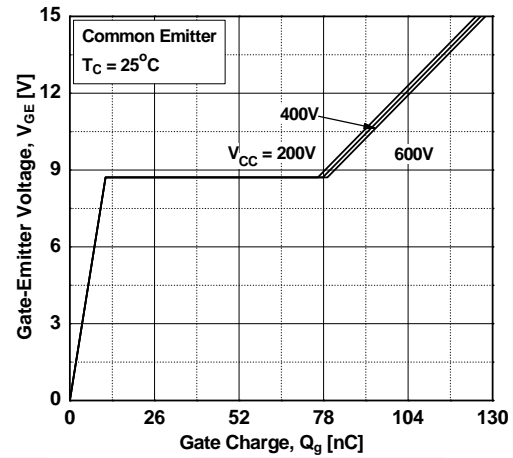


Figure 9. Turn-on Characteristics vs. Gate Resistance

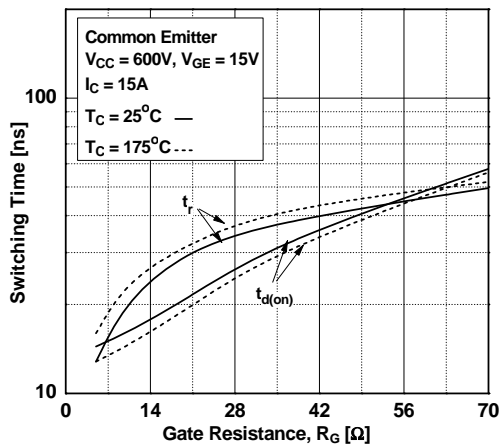


Figure 10. Turn-off Characteristics vs. Gate Resistance

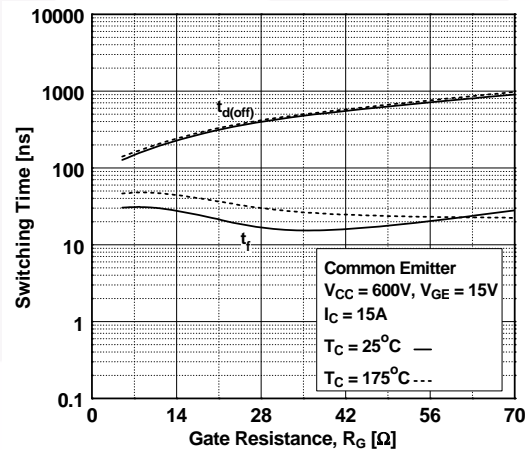


Figure 11. Switching Loss vs. Gate Resistance

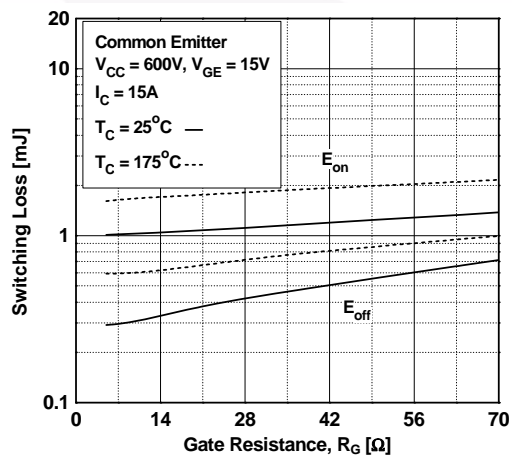
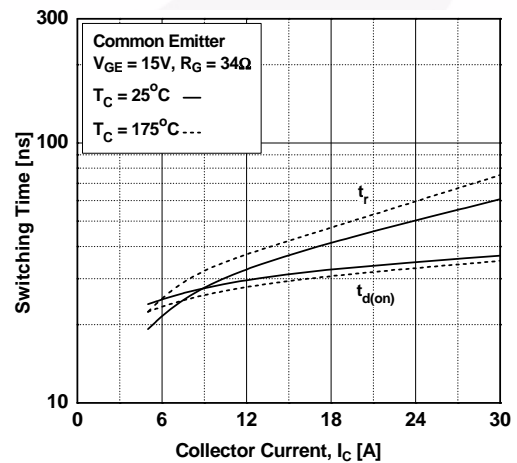


Figure 12. Turn-on Characteristics vs. Collector Current



## Typical Performance Characteristics

Figure 13. Turn-off Characteristics vs. Collector Current

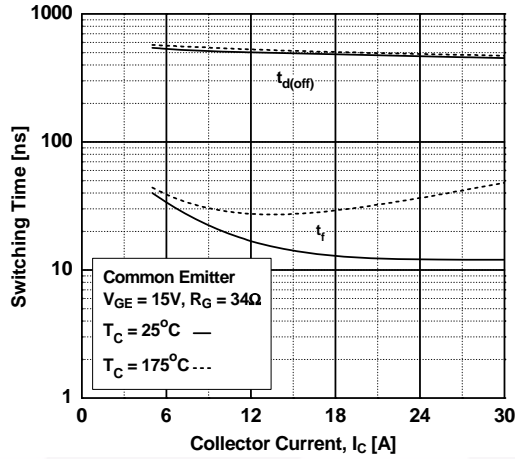


Figure 14. Switching Loss vs. Collector Current

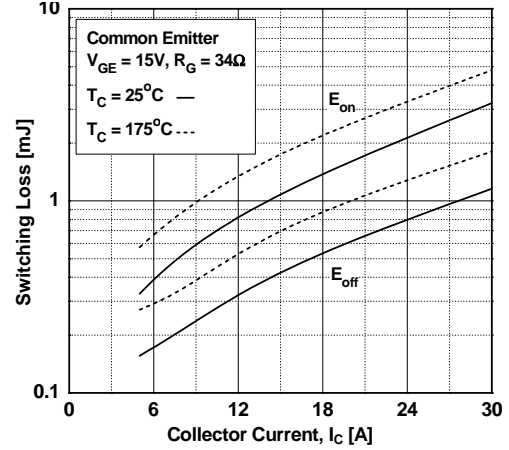


Figure 15. Load Current vs. Frequency

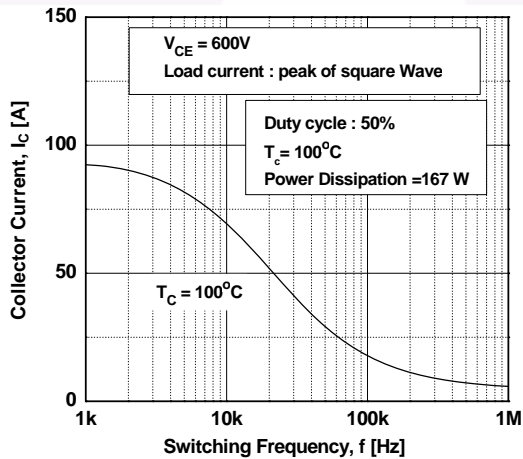


Figure 16. SOA Characteristics

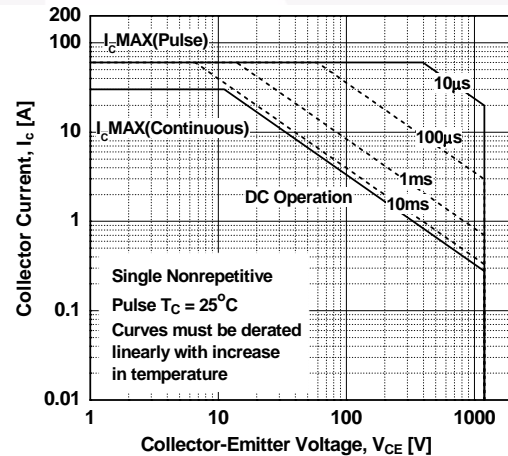


Figure 17. Forward Characteristics

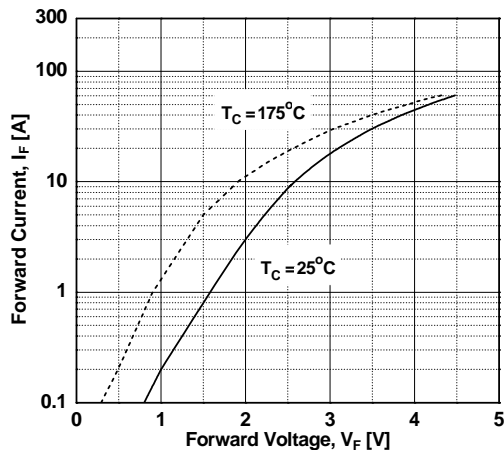
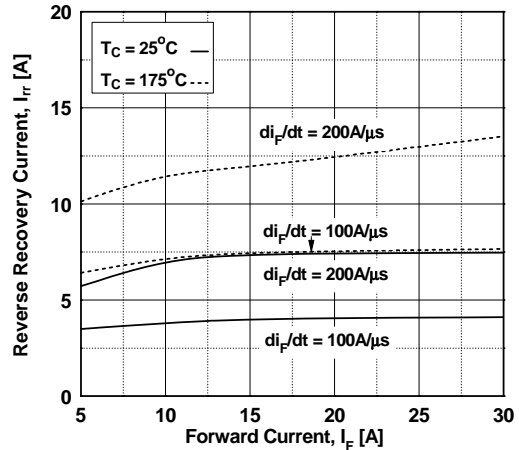


Figure 18. Reverse Recovery Current



## Typical Performance Characteristics

Figure 19. Reverse Recovery Time

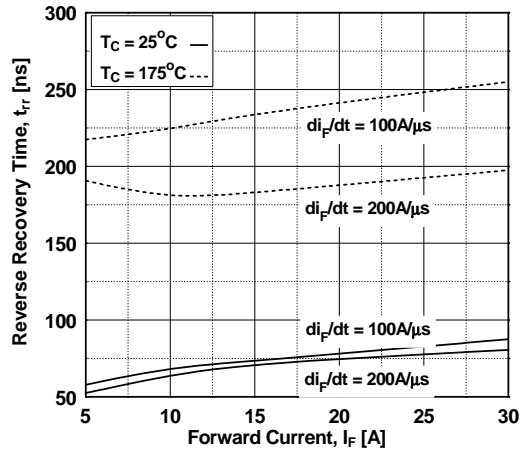


Figure 20. Stored Charge

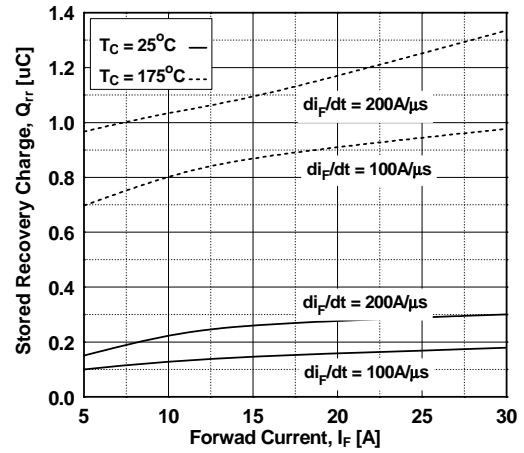


Figure 21. Transient Thermal Impedance of IGBT

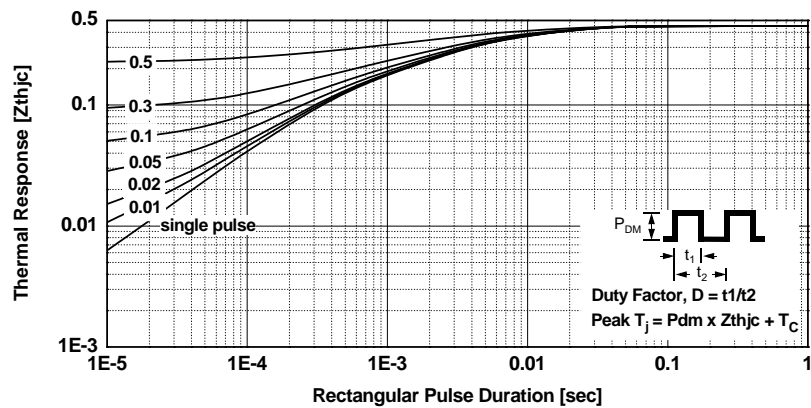
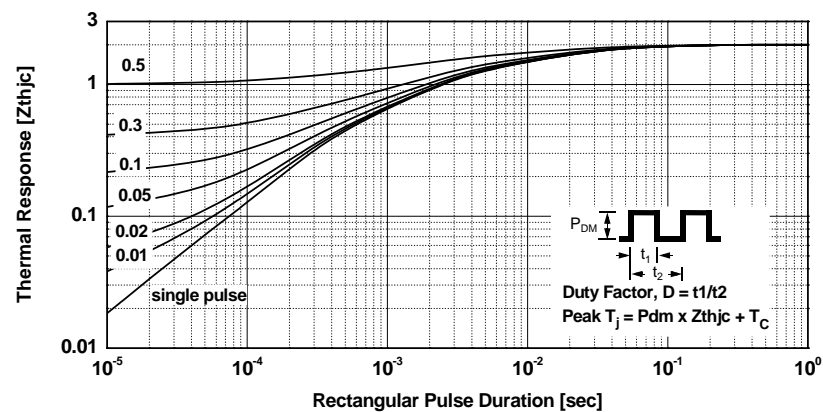
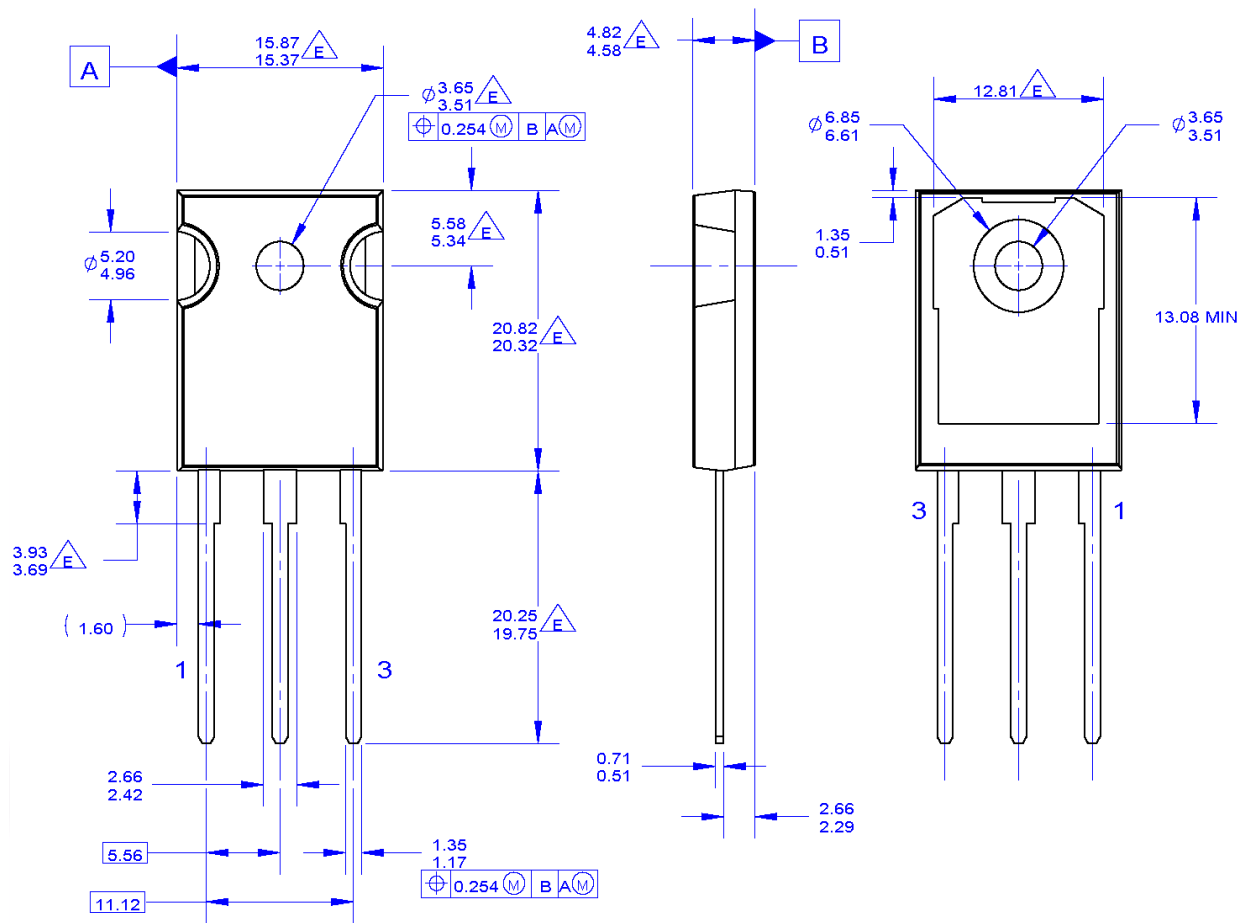


Figure 22. Transient Thermal Impedance of Diode





## Mechanical Dimensions



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- D. DRAWING CONFORMS TO ASME Y14.5 - 1994

**(E)** DOES NOT COMPLY JEDEC STANDARD VALUE  
 F. DRAWING FILENAME: MKT-TO247G03\_REV01

**Figure 23. TO-247, MOLDED, 3 LEAD, JEDEC AB LONG LEADS (Active)**

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Dimensions in Millimeters



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Для оперативного оформления запроса Вам необходимо перейти по данной ссылке:

<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

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